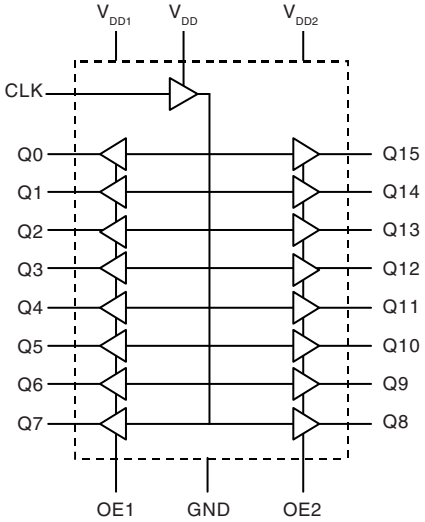
General Description

The 8343-01 is a low skew, 1-to-16 LVCMOS/LVTTL Fanout Buffer. The 8343-01 single ended clock input accepts LVCMOS or LVTTL input levels. The ICS8343-01 operates at 3.3V, 2.5V and mixed 3.3V input and 2.5V supply modes over the commercial temperature range. Guaranteed output and part-to-part skew characteristics make the 8343-01 ideal for those clock distribution applications demanding well defined performance and repeatability.

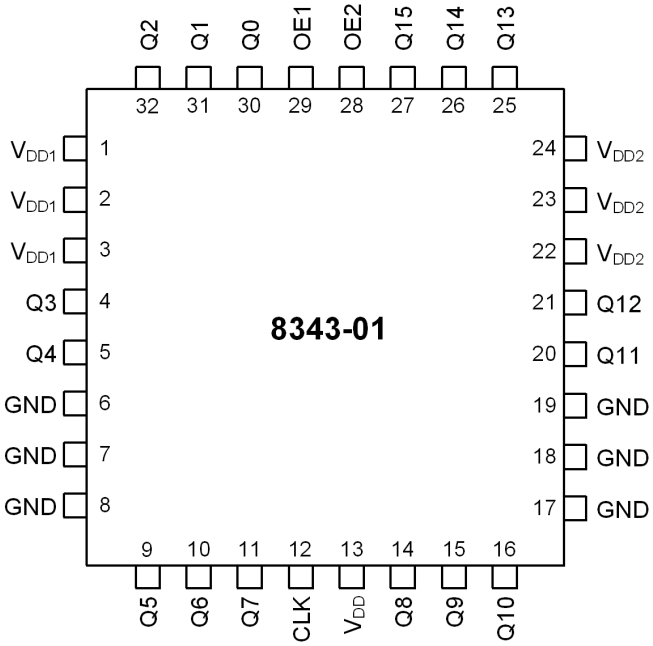
Features

- 16 LVCMOS/LVTTL outputs
- One LVCMOS/LVTTL clock input
- CLK can accept the following input levels: LVCMOS, LVTTL
- Maximum output frequency: 200MHz
- Dual output enable inputs facilitates 1-to-16 or 1-to-8 input to output modes
- All inputs are 5V tolerant
- Output skew: 250ps (maximum)
- Part-to-part skew: 700ps (maximum)
- Full 3.3V and 2.5V or mixed 3.3V core/2.5V operating supply
- 0°C to 70°C ambient operating temperature
- Lead-Free packaging
- Industrial temperature information available upon request

Block Diagram



Pin Assignment



32-Lead LQFP
7mm x 7mm x 1.4mm body package
Y Package
(Top View)

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Pin Descriptions and Characteristics

Table 1. Pin Descriptions[1]

Number	Name	Type		Description
1	V_{DD1}	Power		Q0 through Q7 output supply pin.
2	V_{DD1}	Power		Q0 through Q7 output supply pin.
3	V_{DD1}	Power		Q0 through Q7 output supply pin.
4	Q3	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
5	Q4	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
6	GND	Power		Power supply ground.
7	GND	Power		Power supply ground.
8	GND	Power		Power supply ground.
9	Q5	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
10	Q6	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
11	Q7	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
12	CLK	Input	Pulldown	LVCMOS/LVTTL clock input / 5V tolerant.
13	V_{DD}	Power		Core supply pin.
14	Q8	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
15	Q9	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
16	Q10	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
17	GND	Power		Power supply ground.
18	GND	Power		Power supply ground.
19	GND	Power		Power supply ground.
20	Q11	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
21	Q12	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
22	V_{DD2}	Power		Q8 through Q15 output supply pin.
23	V_{DD2}	Power		Q8 through Q15 output supply pin.
24	V_{DD2}	Power		Q8 through Q15 output supply pin.
25	Q13	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
26	Q14	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
27	Q15	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
28	OE2	Input	Pullup	Output enable. When low forces outputs Q8 through Q15 to HiZ state. 5V tolerant. LVCMOS/LVTTL interface levels.
29	OE1	Input	Pullup	Output enable. When low forces outputs Q0 through Q7 to HiZ state. 5V tolerant. LVCMOS/LVTTL interface levels.
30	Q0	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
31	Q1	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.
32	Q2	Output		LVCMOS/LVTTL clock output. 7Ω typical output impedance.

NOTE 1: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, *Pin characteristics*, for typical values.

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Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C_{IN}	Input Capacitance			4		pF
C_{PD}	Power Dissipation Capacitance (per output)	V_{DD}, V_{DD1}, V_{DD2} = 3.465V		11		pF
		V_{DD1}, V_{DD2} = 2.63V		9		pF
R_{PULLUP}	Input Pullup Resistor			51		kΩ
$R_{PULLDOWN}$	Input Pulldown Resistor			51		kΩ
R_{OUT}	Output Impedance	V_{DD}, V_{DD1}, V_{DD2} = 3.3V	5	7	12	Ω

Table 3. Function Table[1]

Inputs		Outputs	
OE1	**OE2**	**Q0:Q7**	**Q8:Q15**
0	0	HiZ	HiZ
1	0	Active	HiZ
0	1	HiZ	Active
1	1	Active	Active

NOTE 1: OE1 and OE2 are 5V tolerant.

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Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *Section , "DC Electrical Characteristics" or AC Electrical Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V_{DD}	4.6V
Inputs, V_I	-0.5V to V_{DD} + 0.5V
Outputs, V_O	-0.5V to V_{DDx} + 0.5V
Storage Temperature, T_{STG}	-65°C to 150°C
Maximum Junction Temperature, TJ_{MAX}	125°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, V_{DD} = 3.3V ±5%, V_{DD1} = V_{DD2} = 3.3V ±5% or 2.5V ±5%, T_A = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Core Supply Voltage		3.135	3.3	3.465	V
V_{DDx}	Output Supply Voltage[1]		3.135	3.3	3.465	V
			2.375	2.5	2.625	V
I_{DD}	Power Supply Current				35	mA
I_{DDx}	Output Supply Current[2]				14	mA

NOTE 1: V_{DDx} denotes V_{DD1} and V_{DD2}.

NOTE 2: I_{DDx} denotes the sum of I_{DD1} and I_{DD2}.

Table 4B. Power Supply DC Characteristics, V_{DD} = V_{DD1} = V_{DD2} = 2.5V ±5%, T_A = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Core Supply Voltage		2.375	2.5	2.625	V
V_{DDx}	Output Supply Voltage[1]		2.375	2.5	2.625	V
I_{DD}	Power Supply Current				34	mA
I_{DDx}	Output Supply Current[2]				13	mA

NOTE 1: V_{DDx} denotes V_{DD1} and V_{DD2}.

NOTE 2: I_{DDx} denotes the sum of I_{DD1} and I_{DD2}.

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Table 4C. LVCMOS / LVTTL DC Characteristics, $V_{DD} = V_{DD1} = V_{DD2} = 3.3V \pm 5\%$ or $2.5V \pm 5\%$, $V_{DD} = 3.3V \pm 5\%$, $V_{DD1} = V_{DD2} = 2.5V \pm 5\%$, $T_A = 0°C$ to $70°C$

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage	OE1, OE2		2		$V_{DD} + 0.3$	V
		CLK		2		$V_{DD} + 0.3$	V
V_{IL}	Input Low Voltage	OE1, OE2		-0.3		0.8	V
		CLK		-0.3		1.3	V
I_{IH}	Input High Current	OE1, OE2	$V_{DD} = V_{IN} = 3.465V$ or $2.625V$			5	µA
		CLK	$V_{DD} = V_{IN} = 3.465V$ or $2.625V$			150	µA
I_{IL}	Input Low Current	OE1, OE2	$V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$	-150			µA
		CLK	$V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$	-5			µA
V_{OH}	Output High Voltage[1]		$V_{DD1} = V_{DD2} = 3.465V$	2.6			V
			$V_{DD1} = V_{DD2} = 2.625V$	1.8			V
V_{OL}	Output Low Voltage		$V_{DD1} = V_{DD2} = 3.465V$ or $2.625V$			0.5	V
I_{OZL}	Output Tristate Current Low					5	µA
I_{OZH}	Output Tristate Current High					5	µA

NOTE 1: Outputs terminated with 50Ω to V_{DDx} /2. See Parameter Measurement Information, “Output Load Test Circuit Diagrams”.

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AC Electrical Characteristics

Table 5A. AC Electrical Characteristics, $V_{DD} = V_{DD1} = V_{DD2} = 3.3V \pm 5\%$, $T_A = 0°C$ to $70°C$[1]

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Output Frequency				200	MHz
t_{pLH}	Propagation Delay[2]	$f \leq 200$MHz	2.0		4.0	ns
*t*sk(o)	Output Skew[3, 4]	Measured on rising edge @ $V_{DDx}/2$			250	ps
*t*sk(pp)	Part-to-Part Skew[4, 5]	Measured on rising edge @ $V_{DDx}/2$			700	ps
t_R / t_F	Output Rise/ Fall Time	20% to 80%	0.4		1.5	ns
odc	Output Duty Cycle	$f \leq 133$MHz	45		55	%
t_{PW}	Output Pulse Width	$f > 133$MHz	$t_{PERIOD}/2 - 0.25$	$t_{PERIOD}/2$	$t_{PERIOD}/2 + 0.25$	ns

NOTE 1: All parameters measured at f_{MAX} unless noted otherwise.

NOTE 2: Measured from $V_{DD}/2$ of the input to $V_{DDx}/2$ of the output.

NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{DDx}/2$.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 5: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DDx}/2$.

Table 5B. AC Electrical Characteristics, V_{DD} 3.3V ±5%, $V_{DD1} = V_{DD2} = 2.5V \pm 5\%$, $T_A = 0°C$ to $70°C$[1]

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Output Frequency				200	MHz
t_{pLH}	Propagation Delay[2]	$f \leq 200$MHz	2.0		4.5	ns
*t*sk(o)	Output Skew[3, 4]	Measured on rising edge @ $V_{DDx}/2$			250	ps
*t*sk(pp)	Part-to-Part Skew[4, 5]	Measured on rising edge @ $V_{DDx}/2$			700	ps
t_R / t_F	Output Rise/ Fall Time	20% to 80%	0.4		1.0	ns
odc	Output Duty Cycle	$f \leq 133$MHz	40		60	%

NOTE 1: All parameters measured at f_{MAX} unless noted otherwise.

NOTE 2: Measured from $V_{DD}/2$ of the input to $V_{DDx}/2$ of the output.

NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{DDx}/2$.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 5: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DDx}/2$.

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Table 5C. AC Electrical Characteristics, $V_{DD} = V_{DD2} = 3.3V \pm 5\%$, $V_{DD1} = 2.5V \pm 5\%$, $T_A = 0°C$ to $70°C$[1]

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Output Frequency				200	MHz
*t*sk(o)	Output Skew[2]	Measured on rising edge @ $V_{DDx}/2$			250	ps

NOTE 1: All parameters measured at f_{MAX} unless noted otherwise.

NOTE 2: Defined as skew across outputs at the same supply voltages within a bank, and with equal load conditions.

Table 5D. AC Electrical Characteristics, V_{DD} 3.3V ±5%, $V_{DD1} = V_{DD2} = 2.5V \pm 5\%$, $T_A = 0°C$ to $70°C$[1]

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Output Frequency				133	MHz
t_{pLH}	Propagation Delay[2]	$f \leq 200MHz$	2.0		4.0	ns
*t*sk(o)	Output Skew[3, 4]	Measured on rising edge @ $V_{DDx}/2$			250	ps
*t*sk(pp)	Part-to-Part Skew[4, 5]	Measured on rising edge @ $V_{DDx}/2$			1	ns
t_R / t_F	Output Rise/ Fall Time	20% to 80%	0.4		1.0	ns
odc	Output Duty Cycle	$f \leq 133MHz$	40		60	%

NOTE 1: All parameters measured at f_{MAX} unless noted otherwise.

NOTE 2: Measured from $V_{DD}/2$ of the input to $V_{DDx}/2$ of the output.

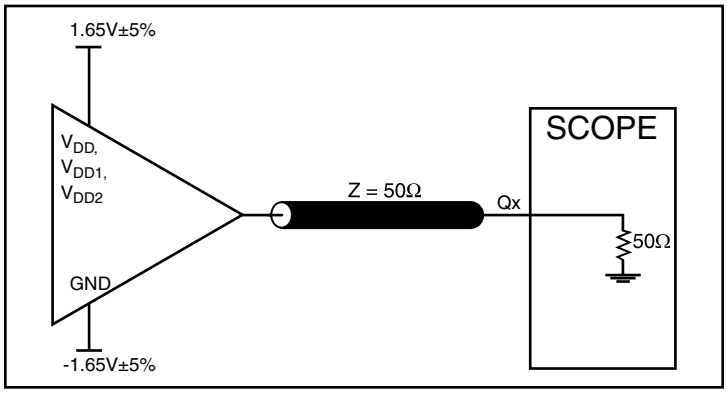
NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{DDx}/2$.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

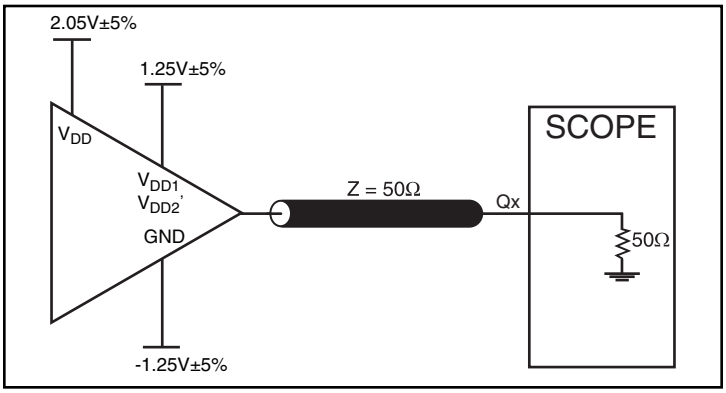
NOTE 5: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DDx}/2$.

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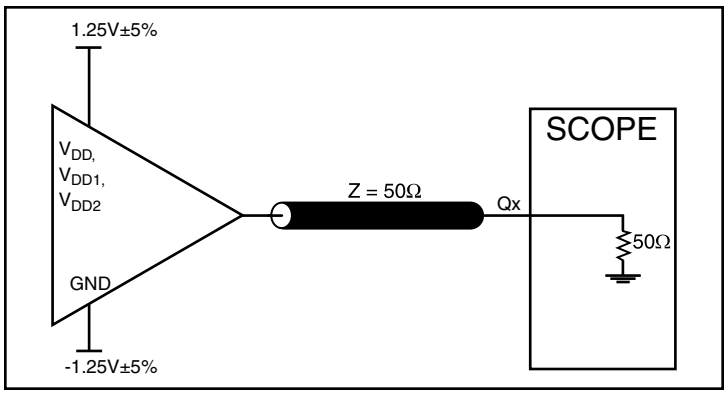
Parameter Measurement Information



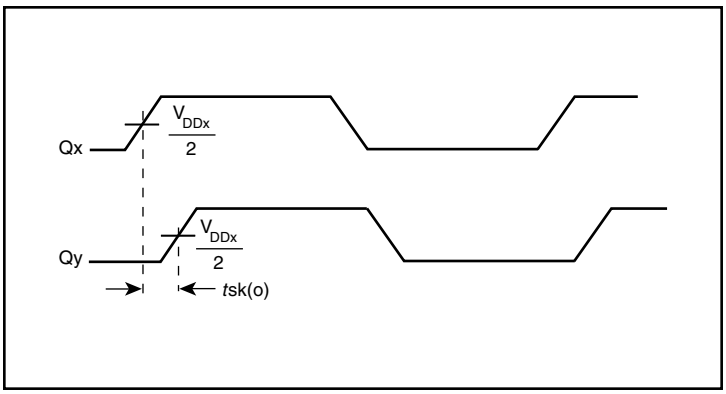
3.3V Core/3.3V Output Load Test Circuit



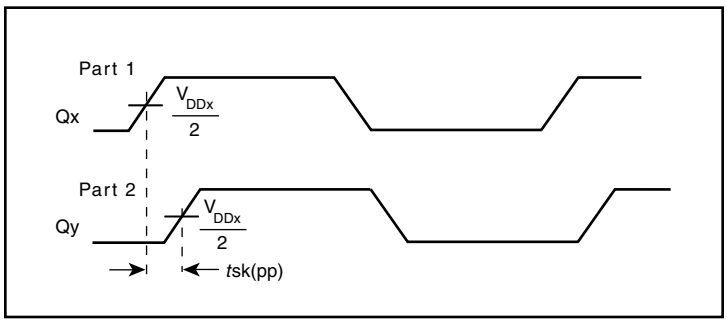
3.3V Core/2.5V Output Load Test Circuit



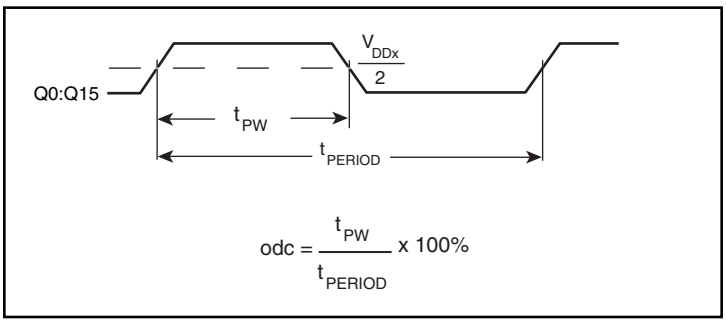
2.5V Core/2.5V Output Load Test Circuit



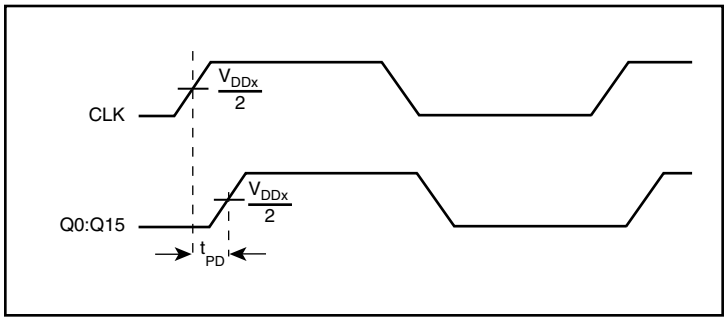
Output Skew



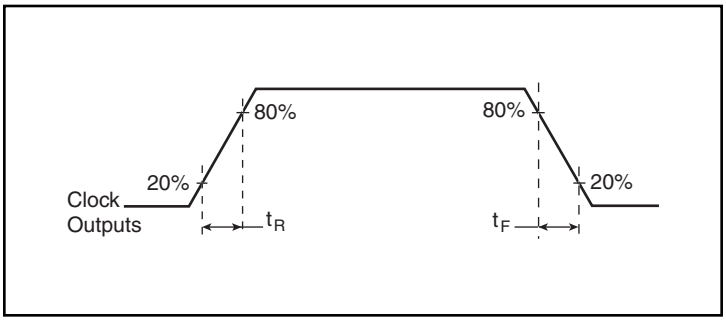
Part-to-Part Skew



Output Duty Cycle/Pulse Width/Period



Propagation Delay



Output Rise/Fall Time

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Reliability Information

Table 6. θ_{JA} vs. Air Flow Table for a 32-Lead LQFP[1]

θ_{JA} by Velocity			
Linear Feet per Minute	**0**	**200**	**500**
Single-Layer PCB, JEDEC Standard Test Boards	67.8°C/W	55.9°C/W	50.1°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	47.9°C/W	42.1°C/W	39.4°C/W

NOTE 1: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

Transistor Count

The transistor count for 8343-01 is 985.

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Package Outline and Package Dimensions

Package Outline - Y Suffix for 32-Lead LQFP

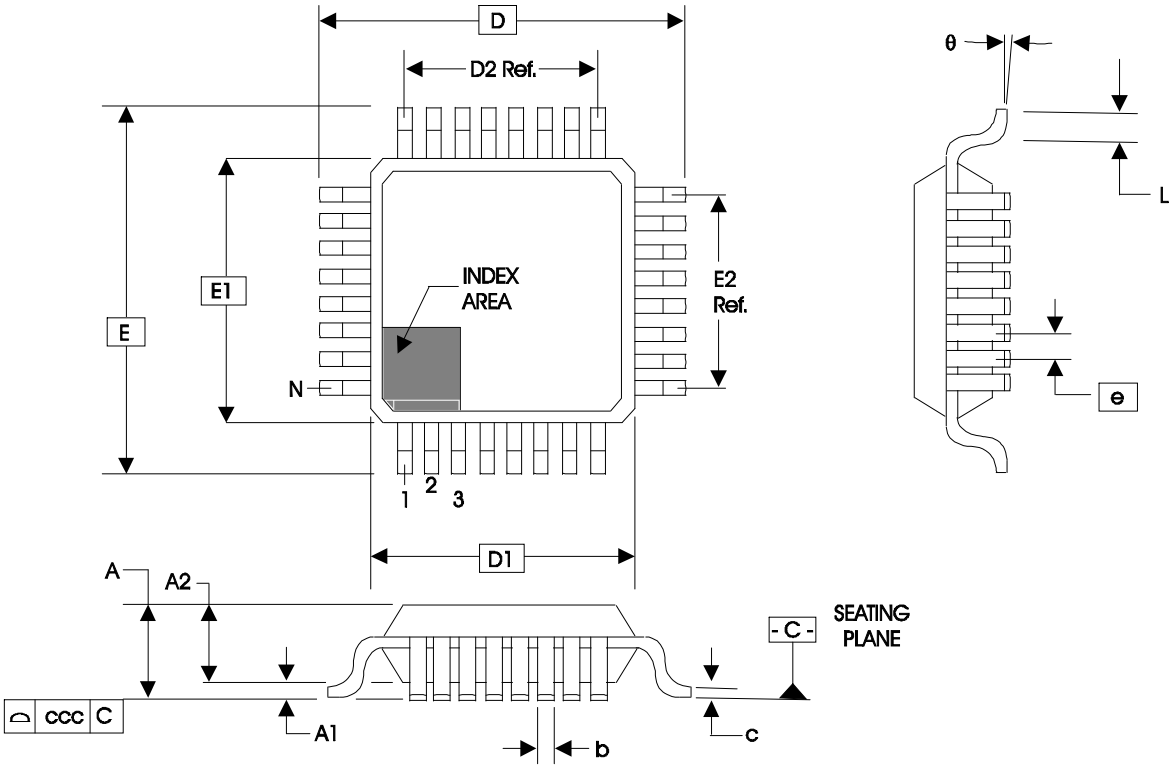


Table 7. Package Dimensions

JEDEC Variation All Dimensions in Millimeters			
Symbol	**Minimum**	**Nominal**	**Maximum**
N		32	
A	–	–	1.60
A1	0.05	–	0.15
A2	1.35	1.40	1.45
b	0.30	0.37	0.45
c	0.09	–	0.20
D		9.00 Basic	
D1		7.00 Basic	
D2		5.60 Ref.	
E		9.00 Basic	
E1		7.00 Basic	
E2		5.60 Ref.	
e		0.80 Basic	
L	0.45	0.60	0.75
θ	0°	–	7°
ccc	–	–	0.10

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Ordering Information

Table 8. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
8343AY-01LF	ICS8343AY01L	“Lead-Free” 32-Lead LQFP	Tray	0°C to 70°C
8343AY-01LFT	ICS8343AY01L	“Lead-Free” 32-Lead LQFP	Tape & Reel	0°C to 70°C

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Revision History Sheet

Rev	Table	Page	Description of Change	Date
A	T2	2	Pin Characteristics Table - changed C_{IN} 4pF max to 4pF typical. Added to R_{OUT}, 5Ω min. and 12Ω max.	9/18/03
	T8	11	Ordering Information correct package column from 48 Lead to 32 Lead.	
B	T5C	5	Added Mixed AC Characteristics Table. Updated format.	8/13/04
B	T8	9	Added Lead-Free marking to Ordering Information Table.	9/16/04
B			Updated format and contact information.	8/25/14
		1	General Description: Deleted HiPerClockS reference.	
	T1	2	Re-organized table sequentially.	
	T8	10	Removed leaded option.	

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